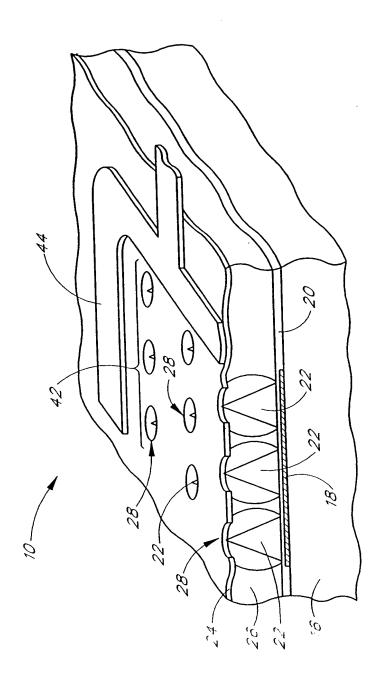


NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE Raina, et al.

Appl. No.: Unknown

Atty Docket: MICRON.111C1

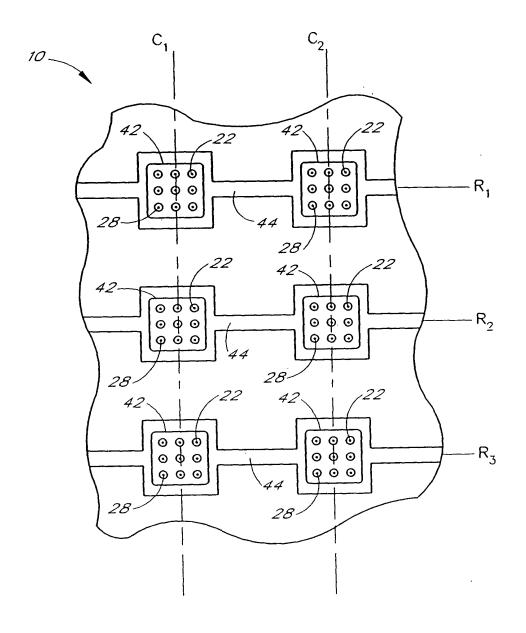


F/G, Z

NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE

Raina, et al.

Appl. No.: Unknown Atty Docket: MICRON.111C1

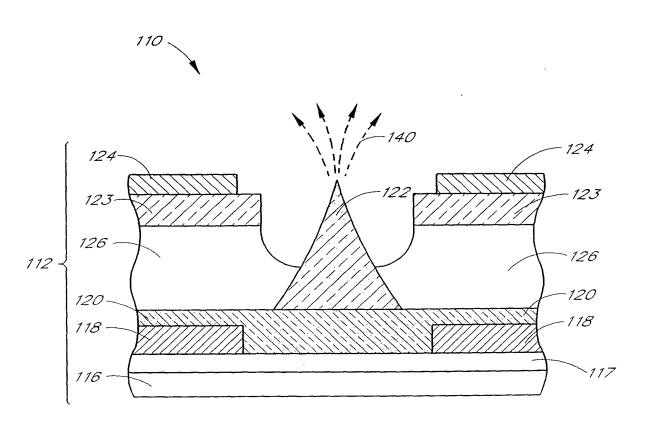


F/G. 3

(PRIOR ART)

Appl. No.: Unknown

Atty Docket: MICRON.111C1



F/G, 4

NITROGEN AND PHOSPHORUS DOPED AMORPHOUS SILICON AS RESISTOR FOR FIELD EMISSION DISPLAY DEVICE BASEPLATE

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Raina, et al.
Atty Docket: MICRON.111C1

FIG. 5